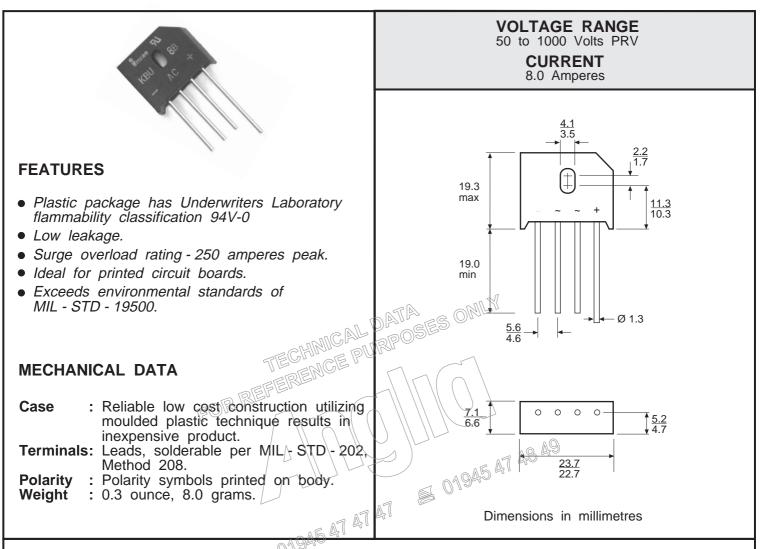


## 8.0 AMPERE SINGLE-PHASE SILICON BRIDGE RECTIFIER

**KBU8 SER** 



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

		KBU8A	KBU8B	KBU8D	KBU8G	KBU8J	KBU8K	KBU8M	
Maximum Recurrent Peak Reverse Voltage	Vrrm	50	100	200	400	600	800	1000	V
Maximum Bridge Input Voltage RMS	Vrms	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
	2) IF(AV)	8.0						A	
Peak Forward Surge Current, 8.3 ms single half sine - wave superimposed on rated load (see Fig	1) IFSM	250						А	
Maximum Forward Voltage Drop per Element at 4.0A (see Fig 3	3) VF	1.0							V
$\begin{array}{llllllllllllllllllllllllllllllllllll$		10.0 1.0							μA mA
Operating Temperature Range	TJ	- 55 to + 125						°C	
Storage Temperature Range	Tstg	- 55 to + 150					°C		

Notes \* Unit mounted on metal heatsink. \*\* Unit mounted on P.C. board.

## RATING AND CHARACTERISTIC CURVES KBU8 SERIES

